



UNITED STATES PATENT AND TRADEMARK OFFICE

COMMISSIONER FOR PATENTS  
UNITED STATES PATENT AND TRADEMARK OFFICE  
WASHINGTON, D.C. 2023  
www.uspto.gov

\*BIBDATASHEET\*

CONFIRMATION NO. 9248

Bib Data Sheet

SERIAL NUMBER 09/916.530	FILING DATE 07/30/2001  RULE	CLASS 438	GROUP ART UNIT 2812	ATTORNEY DOCKET NO. P 0279038 T1HM-98S0740-D
-----------------------------	---------------------------------------	--------------	------------------------	---

APPLICANTS

Katsura Miyashita, Fujisawa-shi, JAPAN; *RP Yes*

Hisao Yoshimura, Kawasaki-shi, JAPAN;  
Mariko Takagi, Kawasaki-shi, JAPAN; *RP Yes*

\*\* CONTINUING DATA \*\*

This application is a DIV of 09/164,343 10/01/1998 ABN *RP Yes*

\*\* FOREIGN APPLICATIONS \*\*

JAPAN 9-268513 10/01/1997 *RP Yes*

IF REQUIRED, FOREIGN FILING LICENSE GRANTED  
\*\* 08/20/2001

Foreign Priority claimed 35 USC 119 (a-d) conditions met	<input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input checked="" type="checkbox"/> yes <input type="checkbox"/> no Met after Allowance	STATE OR COUNTRY JAPAN	SHEETS DRAWING 9	TOTAL CLAIMS 19	INDEPENDENT CLAIMS 7
---	--	------------------------------	------------------------	-----------------------	----------------------------

Verified and Acknowledged  
Examiner's Signature *[Signature]* Initials *[Initials]*

ADDRESS  
909  
PILLSBURY WINTHROP, LLP  
P.O. BOX 10500  
MCLEAN, VA  
22102

TITLE  
Semiconductor device comprising metal silicide films formed to cover gate electrode and source-drain diffusion layers and method of manufacturing the same

FILING FEE  RECEIVED 1372	FEES: Authority has been given in Paper No. _____ to charge/credit DEPOSIT ACCOUNT No. _____ for following:	<input type="checkbox"/> All Fees <input type="checkbox"/> 1.16 Fees ( Filing ) <input type="checkbox"/> 1.17 Fees ( Processing Ext. of time ) <input type="checkbox"/> 1.18 Fees ( Issue ) <input type="checkbox"/> Other _____ <input type="checkbox"/> Credit
------------------------------------	---	---

*RP 12-2003*

*where in the silicide on gate is thicker than on source-drain*